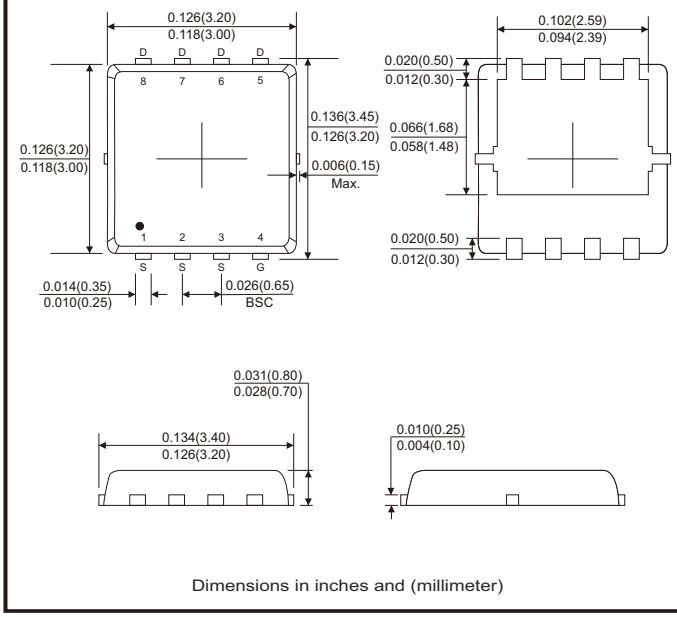
CMS35N04V8-HF

N-Channel
RoHS Device
Halogen Free

Features

- Advanced DMOS trench technology.
- Fast switching.
- Improve dv/dt capability.
- Green device available.
- 100% EAS guaranteed.

PDFN3.3x3.3(SPR-PAK)



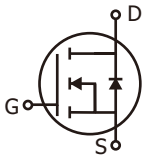
Dimensions in inches and (millimeter)

Mechanical data

- Case: PDFN3.3x3.3/SPR-PAK standard package, molded plastic.

Circuit diagram

- G : Gate
- S : Source
- D : Drain



Maximum Ratings

Parameter	Conditions	Symbol	Value	Unit
Drain-source voltage		V_{DS}	40	V
Gate-source voltage		V_{GS}	±20	V
Continuous drain current (Note 1)	I_D @ T_C = 25°C		35	A
	I_D @ T_C = 100°C		22.1	
Pulsed drain current (Note 1, 2)		I_{DM}	140	A
Total power dissipation (Note 4)	P_D @ T_C = 25°C		44	W
	P_D @ T_A = 25°C		2	
Single pulse avalanche energy, L=0.1mH (Note 3)		E_{AS}	61	mJ
Single pulse avalanche current, L=0.1mH (Note 3)		I_{AS}	35	A
Operating junction temperature range		T_J	-55 to +150	°C
Storage temperature range		T_{STG}	-55 to +150	°C
Thermal resistance junction-ambient (Note 1)	Steady state	$R_{\theta JA}$	62.5	°C/W
Thermal resistance junction-case (Note 1)	Steady state	$R_{\theta JC}$	2.8	°C/W

Electrical Characteristics (at T_J=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Drain-source breakdown voltage	BV_{DSS}	V_{GS} = 0V, I_D = 250μA	40			V
Gate threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250μA	1.2	1.7	2.5	
Gate-source leakage current	I_{GSS}	V_{GS} = ±20V			±100	nA
Drain-source leakage current (Tj=25°C)	I_{DSS}	V_{DS} = 40V, V_{GS} = 0V			1	μA
Drain-source leakage current (Tj=85°C)		V_{DS} = 32V, V_{GS} = 0V			10	
Static drain-source on-resistance (Note 2)	$R_{DS(on)}$	V_{GS} = 10V, I_D = 10A		7.5	9	mΩ
		V_{GS} = 4.5V, I_D = 8A		11	13.5	
Total gate charge (Note 2)	Q_g	I_D = 8A, V_{DS} = 20V, V_{GS} = 10V		19.7		nC
Gate-source charge	Q_{gs}			2.8		
Gate-drain ("miller") charge	Q_{gd}			5.1		
Turn-on delay time (Note 2)	$t_{d(on)}$	V_{DS} = 15V, V_{GS} = 10V I_D = 1A, R_G = 3.3Ω		13.2		nS
Rise time	t_r			2.2		
Turn-off delay time	$t_{d(off)}$			72		
Fall time	t_f			4.5		
Input capacitance	C_{iss}	V_{GS} = 0V, V_{DS} = 25V, f = 1MHz		1220		pF
Output capacitance	C_{oss}			130		
Reverse transfer capacitance	C_{rss}			55		
Gate resistance	R_g	f = 1MHz		2.2		Ω
Source-drain diode						
Diode forward voltage (Note 2)	V_{SD}	I_S = 10A, V_{GS} = 0V, T_J=25°C			1.2	V
Continuous source current (Note 1, 6)	I_S	V_G = V_D = 0V, Force current			35	A
Pulsed source current (Note 2, 6)	I_{SM}				70	A
Guaranteed avalanche characteristics						
Single pulse avalanche energy (Note 5)	EAS	V_{DD} = 25V, L=0.1mH, I_{AS} = 18A	16.2			mJ

Notes: 1. The data tested by surface mounted on a 1 inch² FR-4 board with 2 oz copper.
2. The data tested by pulsed, pulse width ≤300μs, duty cycle ≤ 2%.
3. The EAS data shows max. rating. The test condition is VDD=25V, VGS=10V, L=0.1mH, IAS=35A.
4. The power dissipation is limited by 150°C junction temperature.
5. The min. value is 100% EAS tested guarantee.
6. The data is theoretically the same as ID and IDM, in real applications, should be limited by total power dissipation.

Rating and Characteristic Curves (CMS35N04V8-HF)

Fig.1 - Drain Current vs. T_C

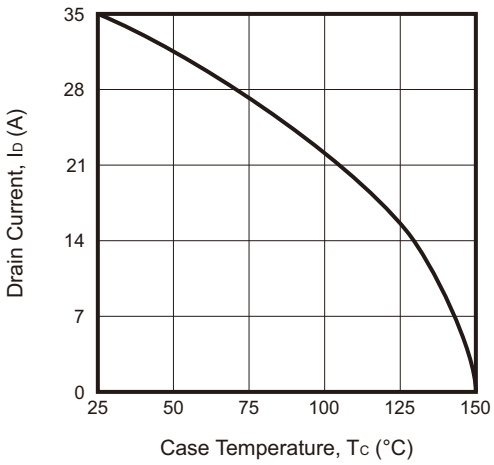


Fig.2 - Gate Charge Characteristics

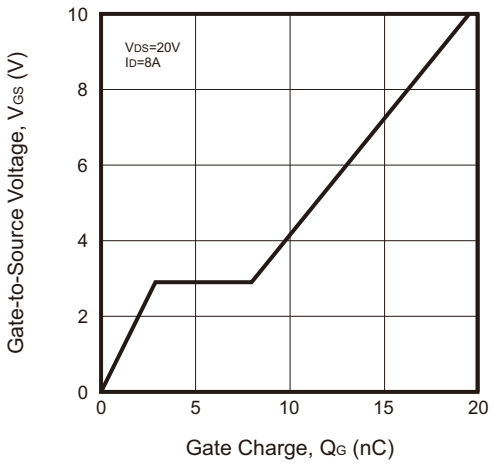


Fig.3 - Normalized $V_{GS(th)}$ vs. T_J

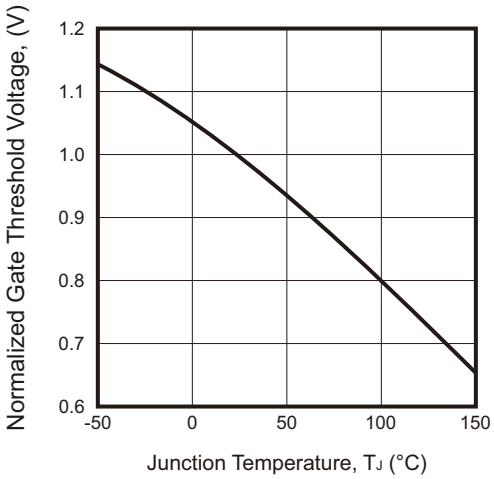


Fig.4 - Normalized $R_{DS(ON)}$ vs. T_J

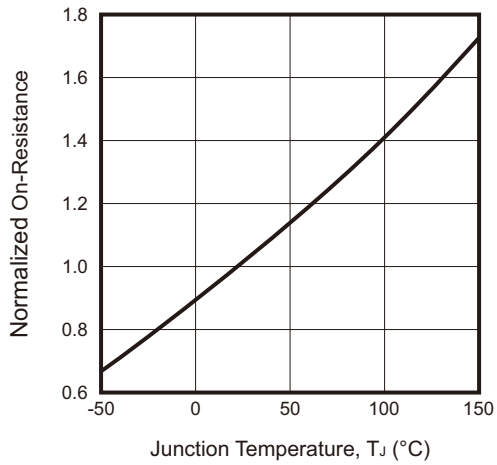
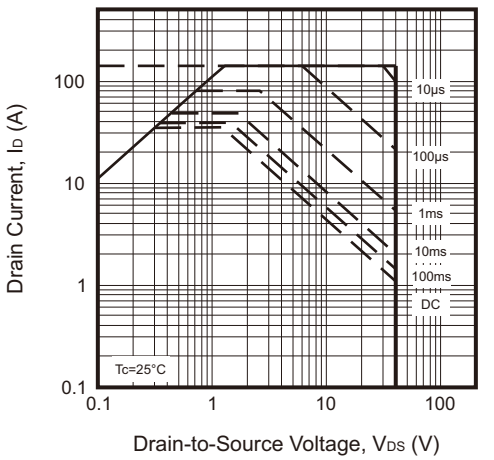
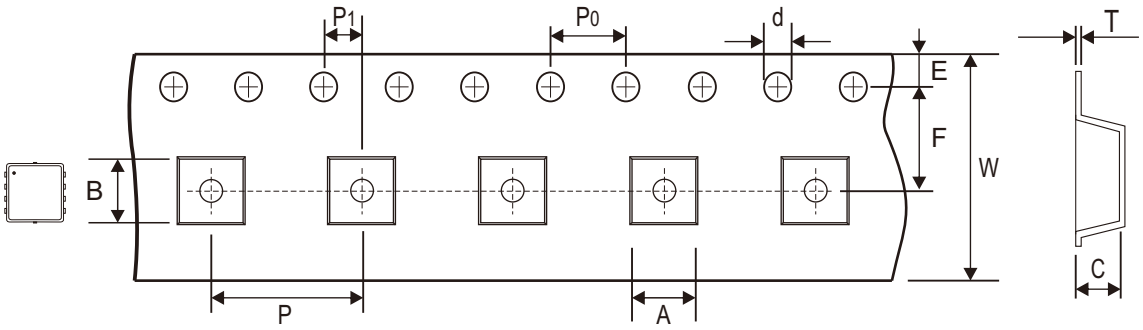


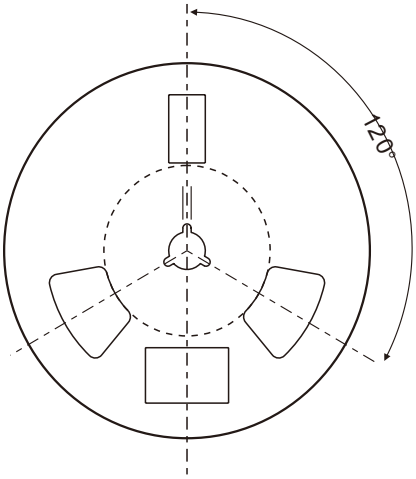
Fig.5 - Safe Operating Area

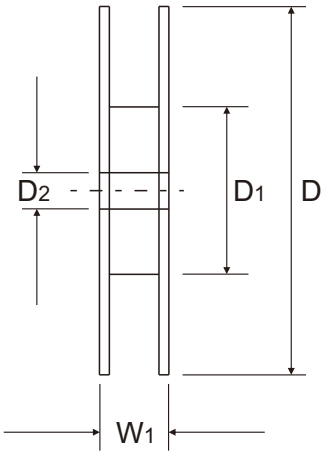


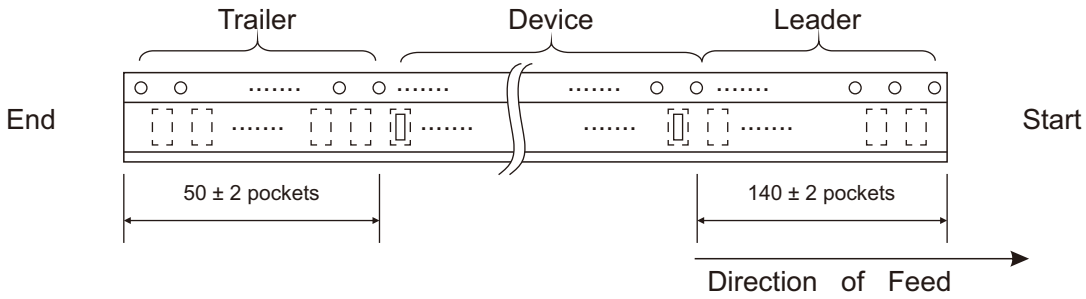
Company reserves the right to improve product design , functions and reliability without notice.

Reel Taping Specification







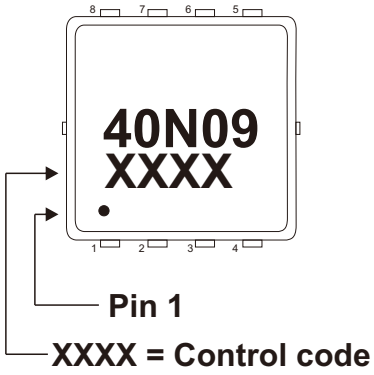


	SYMBOL	A	B	C	d	D	D_1	D_2
SPR-PAK	(mm)	3.55 ± 0.10	3.55 ± 0.10	1.10 + 0.10 - 0.05	1.50 + 0.10 - 0.00	330.00 ± 1.00	178.00 + 0.00 - 2.00	13.00 min.
	(inch)	0.140 ± 0.004	0.140 ± 0.004	0.043 + 0.004 - 0.002	0.059 + 0.004 - 0.000	12.992 ± 0.039	7.008 + 0.000 - 0.079	0.512 min.

	SYMBOL	E	F	P	P_0	P_1	T	W	W_1
SPR-PAK	(mm)	1.75 ± 0.10	5.50 ± 0.05	8.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.05	0.30 ± 0.05	12.00 + 0.30 - 0.10	18.40 ref.
	(inch)	0.069 ± 0.004	0.217 ± 0.002	0.315 ± 0.004	0.157 ± 0.004	0.079 ± 0.002	0.012 ± 0.002	0.472 + 0.012 - 0.004	0.724 ref.

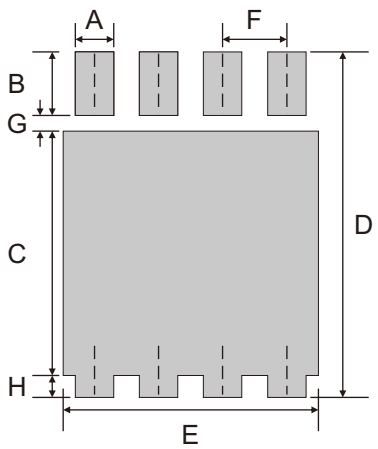
Marking Code

Part Number	Marking Code
CMS35N04V8-HF	40N09



Suggested PAD Layout

SIZE	SPR-PAK (PDFN3.3x3.3)	
	(mm)	(inch)
A	0.40	0.016
B	0.60	0.024
C	2.35	0.093
D	3.55	0.140
E	2.80	0.110
F	0.65	0.026
G	0.35	0.014
H	0.25	0.010



Note: 1. The pad layout is for reference purposes only.

Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
SPR-PAK (PDFN3.3x3.3)	3000	13